

RJH1CM6DPQ-E0

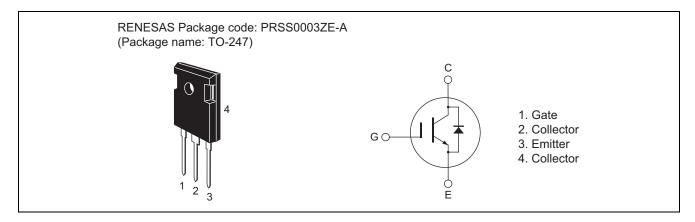
1200V - 20A - IGBT Application: Inverter

R07DS0521EJ0500 Rev.5.00 Jun 24, 2013

Features

- Short circuit withstand time (10 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 2.1 \text{ V typ.}$ (at $I_C = 20 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built-in fast recovery diode ($t_{rr} = 200 \text{ ns typ.}$) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 120 ns typ. (at V_{CC} = 600 V, V_{GE} = 15 V, I_C = 20 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol Ratings		Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	1200	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	Ic	40	А
	Tc = 100°C	Ic	20	Α
Collector peak current		I _C (peak) Note1	60	Α
Collector to emitter diode forward current		I _{DF}	20	Α
Collector to emitter diode forward peak current		I _{DF} (peak) Note1	60	Α
Collector dissipation		P _C Note2	290	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2} 0.43		°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	0.69	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

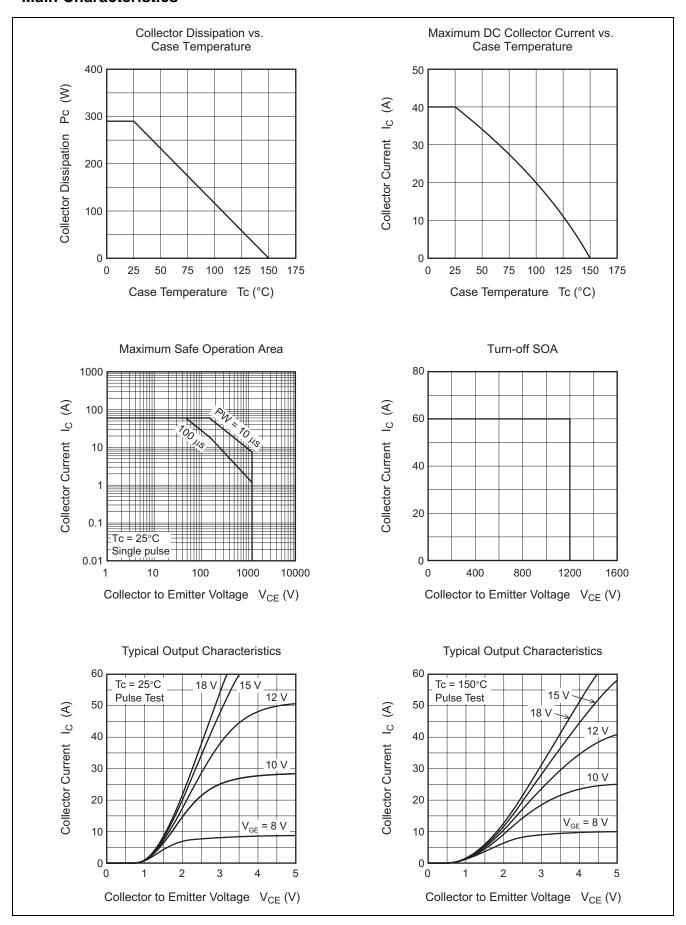
 $(Ta = 25^{\circ}C)$

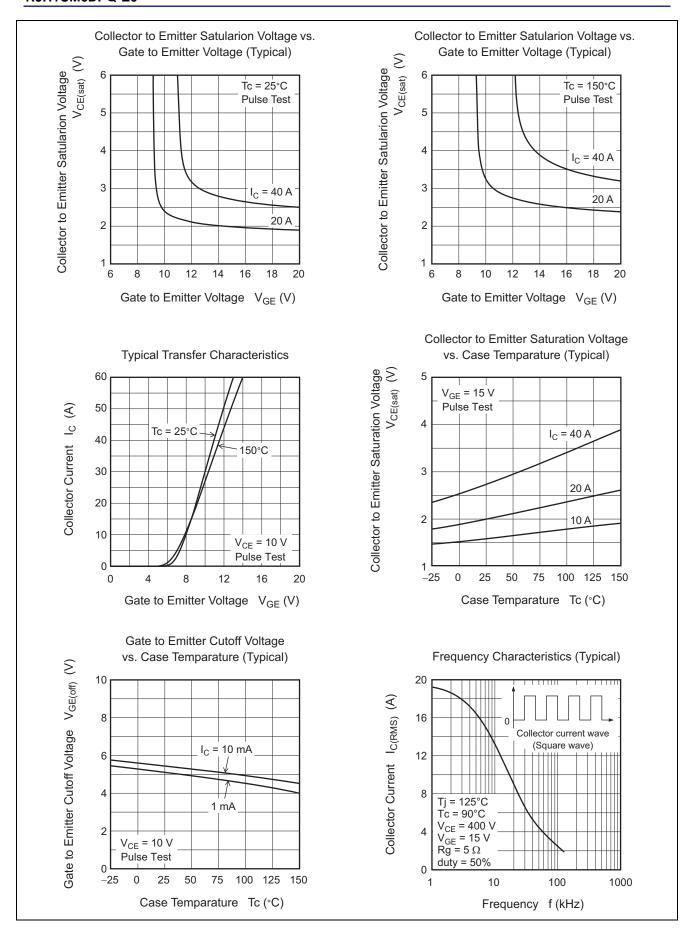
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I _{CES} /I _R	_	_	5	μА	V _{CE} = 1200 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	4.5	_	6.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	2.1	2.7	V	$I_C = 20 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.8	_	V	$I_C = 40 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1600	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	85	_	pF	V _{GE} = 0 f = 1 MHz	
Reveres transfer capacitance	Cres	_	45	_	pF		
Total gate charge	Qg	_	105	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 20 A	
Gate to emitter charge	Qge	_	17.5	_	nC		
Gate to collector charge	Qgc	_	51	_	nC		
Turn-on delay time	t _{d(on)}	_	45	_	ns	V _{CC} = 600 V	
Rise time	t _r	_	21	_	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	120	_	ns	$I_{\rm C} = 20 \text{ A}$	
Fall time	t _f	_	120	_	ns	$Rg = 5 \Omega$	
Turn-on energy	Eon	_	1.8	_	mJ	Inductive load	
Turn-off energy	E _{off}	_	0.9	_	mJ		
Total switching energy	E _{total}	_	2.8	_	mJ		
Short circuit withstand time	t _{sc}	_	10		μs	$V_{CC} \le 720 \text{ V}, V_{GE} = 15 \text{ V}$ $Tc \le 125^{\circ}\text{C}$	
		1	1	1		Note?	
FRD forward voltage	V_{F}	_	1.7	_	V	I _F = 20 A ^{Note3}	
FRD reverse recovery time	t _{rr}	_	180	_	ns	$I_F = 20 \text{ A}$	

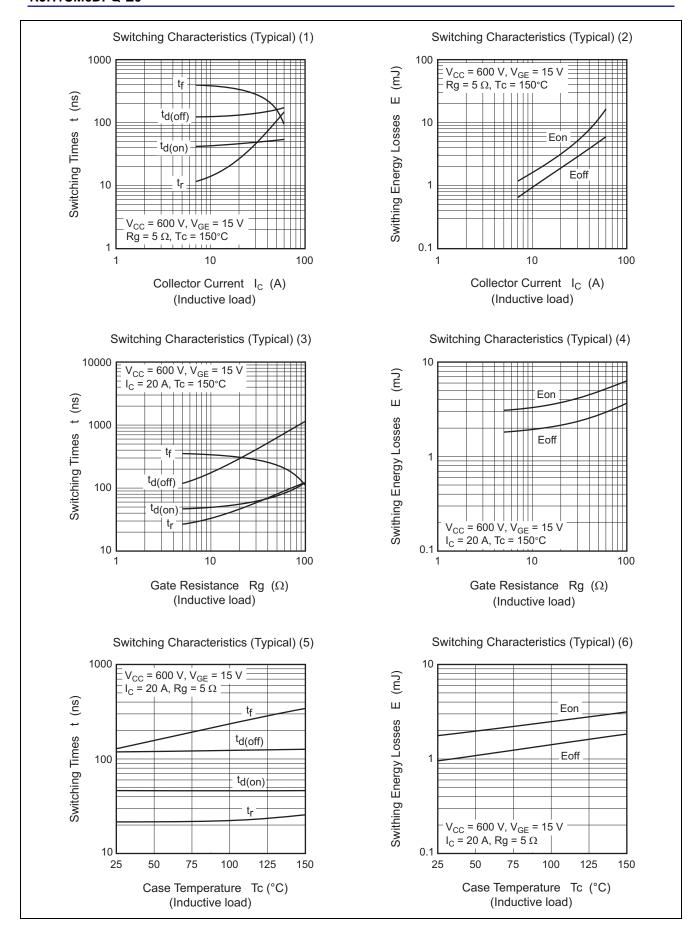
FRD forward voltage	V_{F}	_	1.7	—	V	$I_F = 20 \text{ A}^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	180	_	ns	I _F = 20 A
FRD reverse recovery charge	Q _{rr}	_	0.62	_	μC	$di_F/dt = 100 A/\mu s$
FRD peak reverse recovery current	I _{rr}	_	9.2	_	Α	

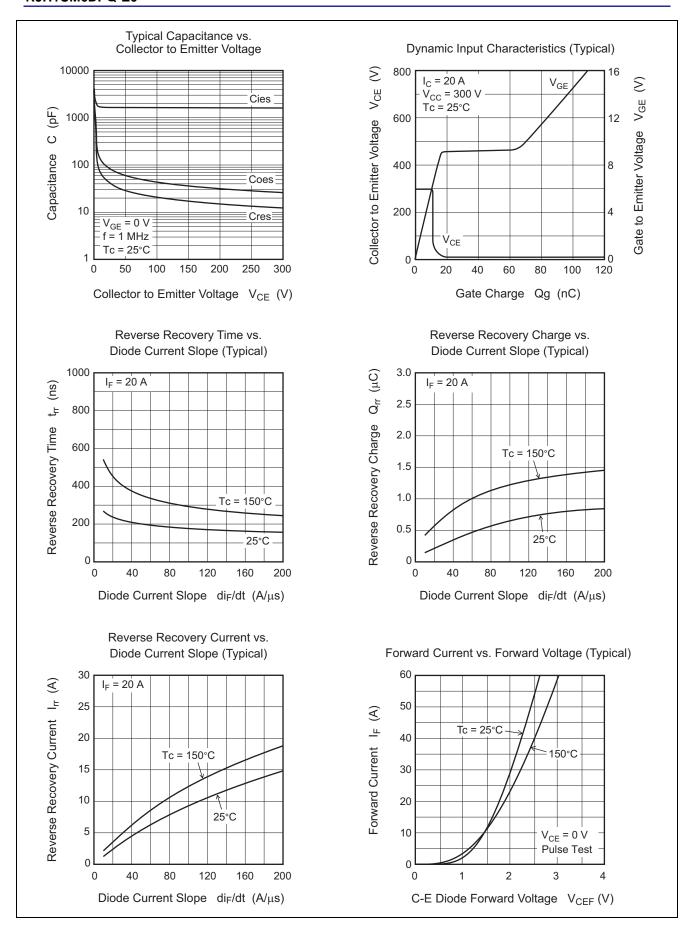
Notes: 3. Pulse test.

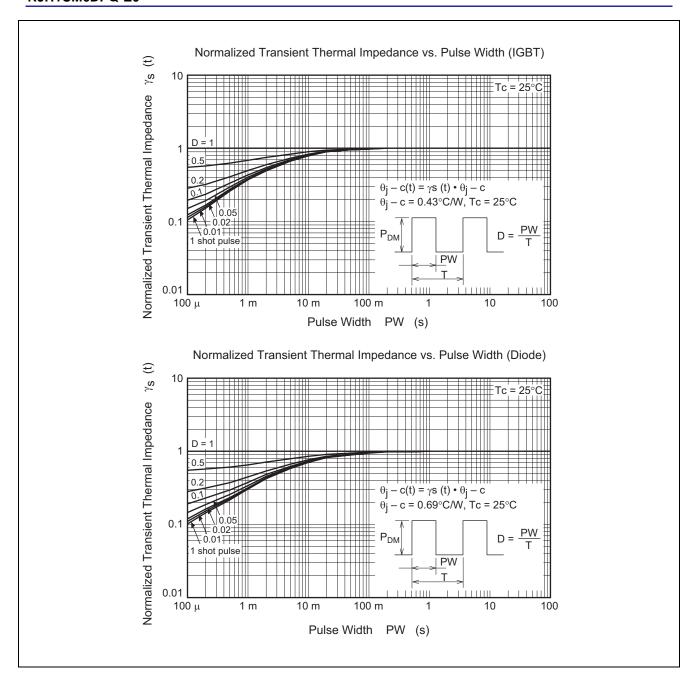
Main Characteristics

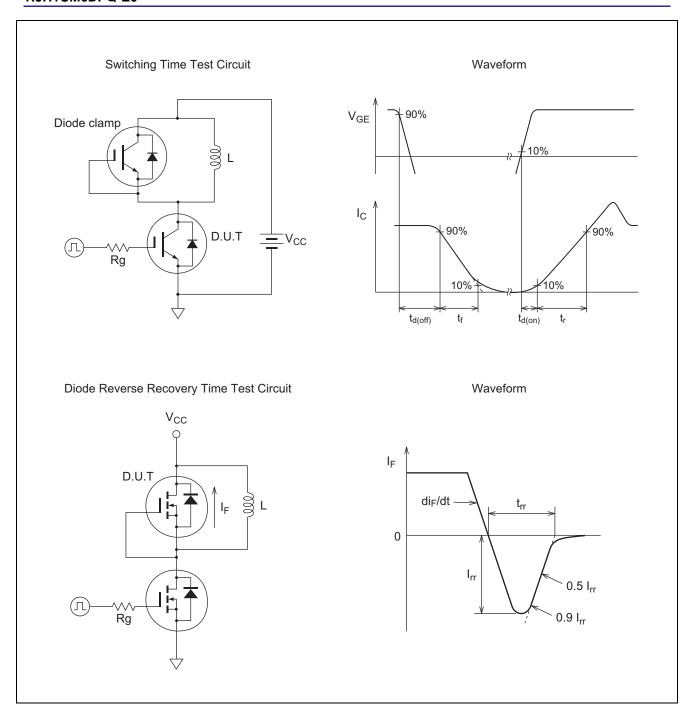




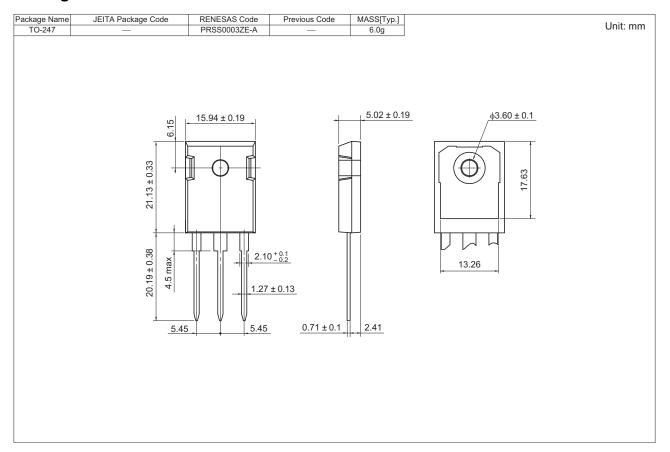








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH1CM6DPQ-E0#T2	450 pcs	Box (Tube)

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